

MICROCIRCUIT DATA SHEET

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SYNCHRONOUS 4-BIT UP/DOWN BINARY COUNTER

General Description

MNMM54C193-X REV 1A0

These up/down counters are monolithic complementary MOS (CMOS) integrated circuits. The MM54C193 is a binary counter.

Counting up and counting down is performed by two count inputs, one being held high while the other is clocked. The outputs change on the positive-going transition of this clock. These counters feature preset inputs that are set when load is a logical "0" and a clear which forces all outputs to "0" when it is at a logical "1". The counters also have carry and borrow outputs so that they can be cascaded using no external circuitry.

Industry Part Number

NS Part Numbers

MM54C193J/883 MM54C193W/883

MM54C193

Prime Die

MM54C193

Processing	Subgrp	Description	Temp ($^{\circ}$ C)
MIL-STD-883, Method 5004	1	Static tests at	+25
	2	Static tests at	+125
	3	Static tests at	-55
Quality Conformance Inspection	4	Dynamic tests at	+25
2	5	Dynamic tests at	+125
MIL CUD-992 Mothod 5005	6	Dynamic tests at	-55
MIL-31D-883, Method 5005	7	Functional tests at	+25
	8A	Functional tests at	+125
	8B	Functional tests at	-55
	9	Switching tests at	+25
	10	Switching tests at	+125
	11	Switching tests at	-55

Features

-	High noise margin	1V guaranteed						
-	Tenth power TTL compatible	Drive	2	LPTTL	loads			
		2			-			

- Wide supply range
- Carry and borrow outputs for N-bit cascading
- Asynchronous clear - High noise immunity

3 V to 15V

0.45 Vcc (typ.)

(Absolute Maximum Ratings)

Voltage at Any Pin	-0 3V to Vcc +0 3V
Operating Temperature Range (TA)	
Storage Temperature Range (Ts)	-55 C LO +125 C
Maximum Vcc Voltage	-65 C to +150 C
	18V
Power Dissipation (Pd) Dual-In-Line Small Outline	700mW 500mW
Operating Vcc Range	3V to 15V
Lead Temperature (TA) (Soldering, 10 seconds)	260 C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Electrical Characteristics

DC PARAMETERS:

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	MAX	UNIT	SUB- GROUPS
Voh	Logical "1" Output Voltage	Vcc = 5V, Iout = -10uA, Vld = Vclr = 1.5V, other inputs at 3.5V			4.5		V	1, 2, 3
		Vcc = 10V, Iout = -10uA, Vld = Vclr = 2V, other inputs at 8V			9		V	1, 2, 3
		Vcc = 4.5V, Iout = -360uA, Vld = Vclr = 0.8V, other inputs at 3V			2.4		V	1, 2, 3
Vol	Logical "0" Output Voltage	Vcc = 5V, Iout = 10uA, Vih = 3V, Vil = 1.5V				0.5	V	1, 2, 3
		Vcc = 10V, Iout = 10uA, Vih = 8V, Vil = 2V				1	V	1, 2, 3
		Vcc = 4.5V, Iout = 360uA, Vih = 3V, Vil = 0.8V				0.4	V	1, 2, 3
Iih	Logical "1" Input Current	Vcc = 15V, Vin = 15V, other inputs at 0				1	uA	1, 2, 3
III	Logical "0" Input Current	Vcc = 15V, Vin = 0V, other inputs at 15V				-1	uA	1, 2, 3
Icc	Quiescent Device Current	Vcc = 15V, Vih = 15V, Vil = 0V				300	uA	1, 2, 3
Isource	Output Source Current	Vcc = 5V, Vout = 0V, Vld = Vclr = 0, other inputs at 5V			-1.75		mA	1
		Vcc = 10V, Vout = 0V, Vld = Vclr = 0, other inputs at 10V			-8		mA	1
Isink	Output Sink Current	Vcc = 5V, Vout = 5V, Vih = 5V, Vil = 0V			1.75		mA	1
		Vcc = 10V, Vout = 10V, Vih = 10V, Vil = 0V			8		mA	1
Vih Lo Vo	Logical "1" Input Voltage	Vcc = 5V	1		3.5		V	1, 2, 3
		Vcc = 10V	1		8		V	1, 3
			1		5.6		V	2
		Vcc = 4.5V, (CMOS to LP)	1		3		V	1, 2, 3
Vil	Logical "0" Input Voltage	Vcc = 5V	1			1.5	V	1, 2, 3
		Vcc = 10V	1			2	V	1, 2, 3
		Vcc = 4.5V, (CMOS to LP)	1			0.8	V	1, 2, 3

Electrical Characteristics

AC PARAMETERS: PROPAGATION DELAY TIME:

(The following conditions apply to all the following parameters, unless otherwise specified.) AC: Cl = 50pF or equivalent impedance provided by diode load.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	МАХ	UNIT	SUB- GROUPS
tPLH	Count Up or Down	Vcc = 5V	2			400	nS	9
			2			500	nS	10, 11
		Vcc = 10V	2			160	nS	9
			2			200	nS	10, 11
tPHL	Count Up or Down	Vcc = 5V	2			400	nS	9
			2			500	nS	10, 11
		Vcc = 10V	2			160	nS	9
			2			200	nS	10, 11
tPHL	Count Up to Carry	Vcc = 5V	2			200	nS	9
			2			250	nS	10, 11
		Vcc = 10V	2			80	nS	9
			2			100	nS	10, 11
tPHL Count Down to Borrow	Count Down to	Vcc = 5V	2			200	nS	9
	BOLLOW		2			250	nS	10, 11
		Vcc = 10V	2			80	nS	9
			2			100	nS	10, 11
tPLH	Load to Q	ad to Q $Vcc = 5V$	2			480	nS	9
			2			600	nS	10, 11
		Vcc = 10V	2			190	nS	9
			2			237	nS	10, 11
tPHL	Load to Q	Vcc = 5V	2			480	nS	9
			2			600	nS	10, 11
		Vcc = 10V	2			190	nS	9
			2			237	nS	10, 11

Electrical Characteristics

AC PARAMETERS:

(The following conditions apply to all the following parameters, unless otherwise specified.) AC: Cl = 50pF or equivalent impedance provided by diode load.

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN- NAME	MIN	МАХ	UNIT	SUB- GROUPS
ts Time Prior to Load that Data must be present	Time Prior to Load that Data	Vcc = 5V	1			160	nS	9
	must be present	Vcc = 10V	1			50	nS	9
tW	Minimum Clear Pulse Width	Vcc = 5V	1			480	nS	9
		Vcc = 10V	1			190	nS	9
tW Minimu Pulse	Minimum Load Pulse Width	Vcc = 5V	1			160	nS	9
		Vcc = 10V	1			65	nS	9
tW Mi Pu	Minimum Count	Vcc = 5V	1			200	nS	9
		Vcc = 10V	1			80	nS	9
fMAX		Vcc = 5V	1		2.5		MHz	9
		Vcc = 10V	1		б		MHz	9
tr,tf	Clock Rise and Fall Time	Vcc = 5V	1			15	uS	9
		Vcc = 10V	1			5	uS	9

Note 1: Parameter tested go-no-go only. Note 2: Tested at 25 C; guaranteed, but not tested at +125 C and -55 C.